

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE
PATENT APPLICATION

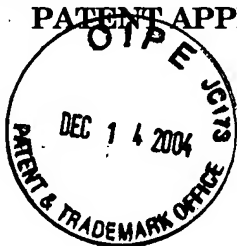
In re Application of:

Visokay et al.

Serial No.: 10/674,771

Filed: 09/30/2003

For: MOS Transistor Gates with Doped Silicide and Methods for Making
the Same



Atty. Docket: TI-35943

Art Unit: 2812

Examiner: V. Mandala

EXTENSION OF TIME

Commissioner for Patents
P. O. Box 1450
Alexandria, VA 22313-1450

CERTIFICATE OF MAILING OR TRANSMISSION

I hereby certify that this correspondence is being deposited
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12-10-04

Jackie McBride
Jackie McBride

Sir:

Pursuant to 37 CFR 1.136(a), Applicant(s) respectfully petitions the Commissioner for
an extension of the shortened statutory period in the above-referenced application.

The fee for this extension is indicated below:

X Two Month (\$450)

Please charge the fee to Deposit Account No. 20-0668. Any further necessary
extension of time is hereby requested. Charge any additional fee or credit any
overpayment to Deposit Account No. 20-0668. This paper is submitted in duplicate.

12/16/2004 BABRAHA1 00000042 200668 10674771

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Respectfully submitted,

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